Theory of polarization enhancement in epitaxial BaT iO 3/SrT iO 3 superlattices

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The spontaneous polarization of epitaxial BaT iO₃/SrT iO₃ superlattices is studied as a function of composition using rst-principles density functional theory within the local density approximation. With the in-plane lattice parameter xed to that of bulk SrT iO₃, the computed superlattice polarization is enhanced above that of bulk BaT iO₃ for superlattices with BaT iO₃ fraction larger than 40%. In contrast to their bulk paraelectric character, the SrT iO₃ layers are found to be tetragonal and polar, possessing nearly the same polarization is the BaT iO₃ layers. General electrostatic arguments elucidate the origin of the polarization in the SrT iO₃ layers, with important implications for other ferroelectric nanostructures.

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Experim ental capabilities now allow layer-by-layerepitaxial growth of perovskite-based oxides, facilitating the exploration of a wide range of arti cial materials inaccessible by conventional solid-state synthesis. Recently, short-period BaT iO 3 / SrT iO 3 superlattices, with modulation lengths down to three perovskite layers, have been grown on SrT iO 3 substrates using pulsed-laser deposition (PLD)¹ and reactive molecular beam epitaxy (MBE).² These superlattices are reportedly free of dislocations and coherently m atched to the substrate, im plying m is t strains of over 2% in the BaT iO 3 layers. Strains of this m agnitude are expected to increase the polarization, $^{3;4}$ and the superlattice geometry preserves the high-strain state and prevents relaxation of the BaT iO $_3$ (BT) layers. But since the BT layers are interleaved with SrT iO $_3$ (ST), which has zero spontaneous polarization in the bulk, the degree to which the overall polarization might be enhanced in the superlattice remains in question.

In this Letter, we address this issue directly through study of a series of ideal short-period BT/ST superlattices with varying composition using rst-principles density functional calculations. Our calculations show that these superlattices are ferroelectric, and predict that some possess polarizations signi cantly larger than bulk BT. An atom ic-level analysis also reveals a signi cant non-zero polarization and strain in the ST layers, a direct result of internal polarizing elds originating in the BT layers. These results, consistent with recent m easurem ents,^{1,2} illustrate the importance of electrical boundary conditions for sustaining polarization in these and other nanoscale ferroelectric m aterials.

To predict the ground state structure and polarization in BT/ST superlattices with various numbers of BT layers, we use density functional theory within the local density approximation (LDA).⁵ A plane-wave basis set and projector-augmented wave potentials⁶ as in plane ented in the V ienna ab initio Simulations Package (VASP)^{7,8} are employed. We consider period- ve superlattices epitaxially grown on ST, and construct 1 1 5 supercells, designated 4/1, 3/2, 2/3, and 1/4, where the notation x/y refers to x perovskite layers of BT and y layers of ST.

The underlying ST substrate is treated in plicitly by constraining the in-plane lattice constant of each superlattice to 3.863 A, the value we calculate for the equilibrium lattice constant of cubic ST. The computed in-plane lattice constant for bulk tetragonal BT (3.945 A) is likewise slightly smaller than experiment, a well-known artifact of the LDA. The resulting m ism atch between the theoretical lattice constants is 2.1%, in excellent agreem ent with that observed experim entally. The ions within each supercell are allowed to relax toward equilibrium along [001], within space group P 4m m (point group C_{4v}), until the Hellm ann-Feynm an forces are less than 10 $^{\rm 3}$ eV /A; the total energy with respect to the norm al (or caxis) lattice parameter of each superlattice is minimized concurrently. Brillouin zone (BZ) integrations are perform ed with a 6 6 2 M onkhorst-Pack m esh. A 44 Ry plane-wave cuto is used for all calculations. For Berryphase polarizations,⁹ we nd that 6 k-points/string along[001] and 6 strings in the irreducible wedge provide wellconverged results.

All calculations are perform ed under periodic, \shortcircuit" boundary conditions, equivalent to a metallic substrate with the lattice constant of ST and full charge compensation on top and bottom \electrode" layers. C anting of polarization toward [111] is found to be energetically unfavorable, although we defer to a future study a full investigation of the possibility of zone-boundary octahedral rotations, such as those present in ST at low tem perature.^{10;11}

The c=a lattice parameters computed for the four period-5 superlattices, as well as those for bulk ST (0/5) and bulk strained BT (5/0), are provided in Table I. W ith the in-plane lattice parameter xed to the com – puted ST lattice constant, the c=a ratio of BT expands to 1.0685 (5 layers = 5.3426 for the 5/0 superlattice), in agreement with the experimentally determined Poisson ratio,^{1;2} and the c=a ratio and cell volume decrease by about 2% per additional SrT iO₃ layer. The decrease in c=a results in a concomitant reduction in the polar distortion within each layer. This is quanti ed by dividing each superlattice into ve Ti-centered unit cells (or

TABLE I. Structural parameters computed for superlattices with in-plane lattice constant a = 3:863 A, and with l_{ST} layers of SrT iO₃ and l_{BT} layers of BaT iO₃ (is their ratio). hc=ai_{\text{BT}}, hc=ai_{\text{ST}}, and hc=ai_I are the average local c/a parameters within BT, ST, and interface layers for each superlattice, as described in the text. P₀=24.97 C/cm² is the computed value for bulk tetragonal BaT iO₃. B lank entries indicate layers absent for a given .

l _{B T} =l _{S T}		c=a	hc=ai _{BT}	hc=ai _{s T}	hc=aiı	P/P ₀
5/0	0	5,3426	1.0685			1.570
4/1	0.25	5,2502	1.0609		1.0338	1.435
3/2	0.667	5.1820	1.0566	1.0077	1.0306	1,249
2/3	1.5	5.1181	1.0526	1.0055	1.0272	1.000
1/4	4	5.0510		1.0018	1.0227	0.520
0/5	1	5.0000		1.0000		0.000

layers), with A cations at the corners, and exam ining local displacem ents from the pseudocubic positions within each layer. The individual perovskite layers are labeled as BT, if bounded by two BaO layers; ST, if bounded by SrO layers; or I, if bounded by one BaO and one SrO layer (one of the two interface layers within the supercell). The distance between neighboring A cations can be regarded as a local c=a; the average values of this ratio for each layer type, hc=ai, appear Table I. The large $hc=ai_{BT}$ are expected, based on the considerable in-plane strain.⁴ M ore surprisingly, the average local c=a of the ST layers deviates slightly from unity: the ST unit cell is evidently expanded within the superlattice relative to the bulk. The strain is accompanied by relative displacements within the ST layers, where in particular we nd the equatorial oxygens (W ycko positions 2c) to move signi cantly o site.

The observed structural trends are re ected in the com puted superlattice polarizations, also given in Table I. Despite the presence of one SrO layer, the polarization of the 4/1 superlattice is predicted to be considerably enhanced over that of BT under standard conditions in the bulk, and also larger than expected if the ST were nonpolar. Replacing one BaO layerwith SrO reduces the polarization by only about 10%, while a simple scaling of the polarization by the volume fraction of BT would result in a 20% reduction. The 3/2 and 2/3 superlattices are found to retain 80 and 64% of the polarization of pure strained BT, again surpassing the scaled values of 60% and 40%. The simple scaling argument is inadequate because it assumes bulk behavior for the ST and strained BT layers, and neglects any electrostatic coupling between them. Internal polarizing elds play an essential role in determ ining the properties of these superlattices, as has been noted previously for other superlattice system s.^{12;13}

To gain insight into the electrostatic coupling between layers, we decompose the total superlattice polarization into contributions from the individual Ti-centered perovskite layers de ned above. (An alternate but equally

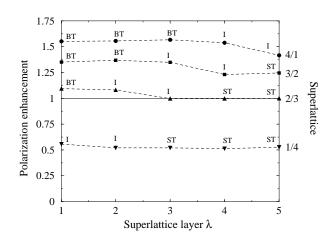


FIG.1. Local polarization enhancement (P /P₀) by layer for each superlattice. Each layer is labeled BT, ST, or I as discussed in the text. A s before, $P_0 = 24.97 \text{ C/cm}^2$.

valid A cation-centered local cell choice does not result in signi cant changes in our analysis.) The local polarization P of cell is expressed as a function of displacem ents within that cell as

$$P = \sum_{i}^{X} \frac{QP}{Qu_{0i}} (u_{i} u_{0i}) = \frac{1}{2} \sum_{i}^{X} U_{i}; \quad (1)$$

where u_i is the displacement of ion i in unit cell , Z_i is the dynamical e ective charge of ion i, and is the volume of the superlattice supercell. (All polarizations and displacements are along [001].) Since there are two di erent apical O ions (corresponding to W ycko positions 1b) associated with the buckled AO plans bounding the cell, we average their contribution to each cell, i.e., $u_{,1b} = \frac{1}{2} (u_{+1;1b} + u_{;1b})$. A similar prescription has previously been used in a study of dom ain walls in PbT iO₃.¹⁴ The dynamical e ective charges are evaluated by nite di erences, in a reference structure with atom ic displacements identically zero within every layer; their values will appear elsewhere.¹⁵

In Figure 1 the local polarization is shown as a function of layer for each superlattice. The most conspicuous feature of these pro les that the local polarization is nearly constant throughout each superlattice, m in im izing electrostatic energy costs associated with the build-up of polarization charge r P at the interfaces. Not only are the ST layers polarized, but their local polarizations are close to those of the BT layers. Notably, the ST polarization, induced by the presence of the BT layers, is signi cant even in the 1/4 superlattice with just a single BaO layer, and even in the absence of in-plane strain. The polarization in the BT layers, on the other hand, is reduced and close in magnitude to that in the ST layers. If the local polarizations of the BT and ST layers were taken as those of the bulk, then the electric elds within the constituent BT and ST layers would be nite and have opposite signs. The eld within the BT layers

would oppose the polarization, and that in the ST layers would polarize the nom inally nonpolar layers.

To exam ine this in more detail, we model the system by two slabs of linear dielectric media, having dielectric constants $_{\rm b}$ and $_{\rm s}$, in a parallel plate geometry. Short-circuit boundary conditions require the electric elds within each slab to be related by ${\rm E}_{\rm b} \, {\rm I}_{\rm BT} = {\rm E}_{\rm s} \, {\rm I}_{\rm ST}$, where ${\rm I}_{\rm BT}$ and ${\rm I}_{\rm ST}$ correspond to the number of layers of BT and ST, as in Table I. Setting their electric displacements D = E + 4 P to be equal, and using P_s = ${}_{\rm s} {\rm E}_{\rm s}$ and P_b = ${}_{\rm b} {\rm E}_{\rm b} + {\rm P}_{5=0}$, the polarization of each of the two slabs can be expressed in terms of the dielectric constants of the two materials, the initial spontaneous polarization, P₅₌₀, of strained BT, and their respective thicknesses. The average of the total slab polarization P, weighted by the num ber of layers of each constituent, then becomes

$$P = \frac{P_{5=0}}{1 + (b = s)};$$
 (2)

= $l_{ST} = l_{BT}$ and $P_{5=0}$ is the computed polarizawhere tion of strained BT, here 39.20 C/m^2 (as in Table I). This macroscopic form ula, valid to linear order in the dielectric constants, can be seen to explain the com position dependence of the superlattice polarization. In Fig.2 we plot the total polarization of each superlattice, calculated rst principles, against . We then perform a onefrom parameter t to this data, obtaining the dashed curve in Fig. 2. Notice that the curve approximates the data rem arkably well, even though our expression for the polarization is derived from m acroscopic electrostatics and the superlattice layers are atom ically thin. Thus to maxim ize the superlattice polarization, one must increase the fraction of BT layers (while preserving the high strain state), consistent with the recent measurem ents of Shim uta et al.¹ It is particularly striking that even for superlattices containing as little as 40% BT, one can expect to achieve a polarization as large as that of bulk BT.

The novel properties of short-period superlattice m aterials are, quite generally, expected to arise from three separatee ects. The rst is the sustainability of large strains in su ciently thin lattice-m ism atched layers. This can produce a signi cant change in properties from the bulk at standard conditions, m anifest here in the enhanced polarization of the BT layers. We also expect electrostatic e ects if the two m aterials have di erent susceptibilities or a polarization m ism atch (i.e., di erent bulk polarizations), as in the present case. Indeed, internal

elds can largely determ ine polarization and structural properties, resulting in a uniform polarization throughout this chem ically inhom ogeneous BT/ST system . Finally, we anticipate changes in properties associated with a high concentration of interfaces, where the bonding and structure will in general depart from that of the interior of the layers or the bulk. W hile in this system the interfaces are relatively gentle, apparently playing a m inor role in the structure and polarization, they m ay be important or even dom inant in other superlattice structures, espe-

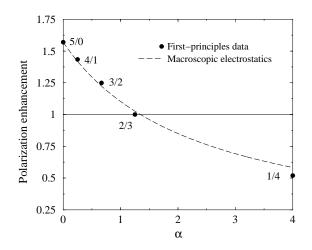


FIG.2. Polarization enhancement ($P = P_0$), computed from rst principles, as a function of $= l_s = l_b$ for each superlattice (lled circles). $_b = _s = 0.4229$ provides the best t of our calculations to Eq. (2).

cially if the thickness of the individual constituent layers is only a few unit cells.

In conclusion, we have shown, using a series of rstprinciples calculations, that signi cant polarization enhancement can be achieved in perovskite oxide superlattices. This enhancement arises from the combined effects of strain, induced in the BT layers by the epitaxial growth, and internal electric elds, associated with the superlattice geometry, which polarize the ST layers. The induced polarization observed here complements a previous prediction of ferroelectricity in ST layers under epitaxial stress.^{3;16} O ur analysis reveals in portant physical factors that in uence the behavior of the superlattice system for given constituent layers and thickness, which will aid in the prediction of properties of a wider class of systems and provide a valuable guide for the design of arti cially-structured materials.

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